THYRISTORS 3P4MH, 3P6MH

3 A MOLD SCR

The 3P4MH and 3P6MH are P-gate fully diffused mold SCRs with an average on-current of 3 A. The repeat peak offvoltages (and reverse voltages) are 400 V and 600 V.

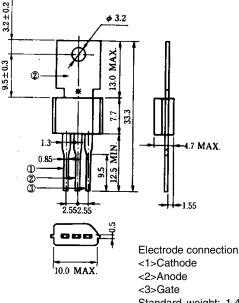
FEATURES

NEC

- · This transistor features a small and lightweight package and is easy to handle even on the mounting surface due to its TO-202AA dimensions. Processing of lead wires and heatsink (tablet) using jigs is also possible.
- Employs flame-retardant epoxy resin (UL94V-0).

APPLICATIONS

Noncontact switches of consumer electronic euipments, electric equipments, audio quipments, and light indutry equipements



PACKAGE DRAWING (UNIT: mm)

*TC test bench-mark

<1>Calnoue	
<2>Anode	
<3>Gate	
Standard weight:	1.4

ABSOLUTE MAXIMUM RATINGS (Ta = 25° C)

Parameter	Symbol	3P4MH	3P6MH	Ratings	Unit
Non-repetitive peak reverse voltage	VRSM	500	700	V	Rgк = 1 k Ω
Non-repetitive peak off-state voltage	VDSM	500	700	V	Rgк = 1 k Ω
Repetitive peak reverse voltage	VRRM	400	600	V	Rgк = 1 k Ω
Repetitive peak off-voltage	VDRM	400	600	V	Rgк = 1 k Ω
Average on-state current	IT(AV)	3 (Tc = 87°C, Single	А	Refer to Figure 11.	
Effective on-state current	IT(RMS)	4	А	_	
Surge on-state current	Ітѕм	65 (f = 50 Hz, Sine half-wave, 1 cycle) 70 (f = 60 Hz, Sine half-wave, 1 cycle)		А	Refer to Figure 2.
Fusing current	∫it²dt	20 (1 ms≤t≤10 ms)		A ² s	-
Critical rate of rise of on-state current	dl⊤/dt	50		A/µs	-
Peak gate power dissipation	Рдм	2 (f≥50 Hz, Duty≤10%)		W	Refer to Figure 3.
Average gate power dissipation	PG(AV)	0.2		W	
Peak gate forward current	IFGM	1 (f≥50 Hz, Duty≤10%)		Α	_
Peak gate reverse voltage	VRGM	6		V	-
Junction temperature	Tj	-40 to +125		°C	-
Storage temperature	Tstg	–55 tp +150		°C	_

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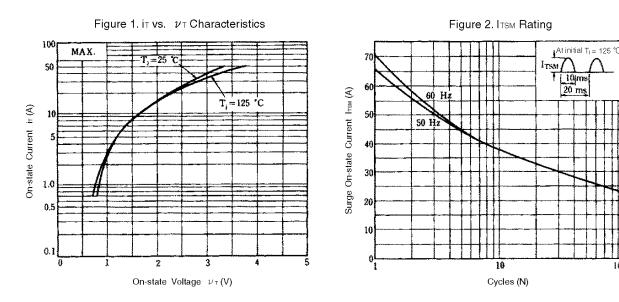
availability and additional information.

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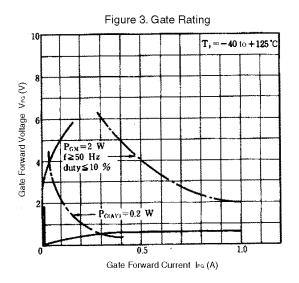
ELECTRICAL CHARACTERISTICS (T_j = 25°C, R_{GK} = 1 k Ω)

Parameter	Symbol	ol Conditions		Specifications			Unit	Remarks
				MIN.	TYP.	MAX.		
Repeat peak reverse	IRRM	VRM = VRRM	$T_j = 25^{\circ}C$	_	-	100	μA	-
current			T _j = 125°C	-	-	2	mA	_
Repeat peak off-current	Idrm	Vdm = Vdrm	$T_j = 25^{\circ}C$	-	-	100	μA	_
			T _j = 125°C	-	-	2	mA	_
Critical rate-of-rise of off- state voltage	dV/dt	$T_{j} = 125^{\circ}C, V_{DM} = \frac{2}{3}V_{DRM}$		_	3	-	V/µs	-
On-state voltage	Vтм	IT = 10 A		-	-	1.6	V	Refer to Figure 1.
Gate trigger current	Ідт	$V_{DM} = 6 V, R_L = 100 \Omega$		-	-	0.2	mA	Refer to Figure 14.
Gate trigger voltage	Vgt	$V_{DM} = 6 V, R_L = 100 \Omega$		-	-	0.8	V	
Gate non-trigger voltage	Vgd	$T_{j} = 125^{\circ}C,$ $V_{DM} = \frac{V_{DRM}}{2}$		0.2	_	-	V	-
Holding current	Ін	Vdm = 24 V, Itm = 10 A		-	1	5	mA	_
Commutating turn-off time	Tq	$T_i = 125$ °C, IT = 3 A, diR/dt = 15 A/μs VR≥25 V, VDM = $\frac{2}{3}$ VDRM dVD/dt = 1 V/μs		-	80	_	μs	_
Thermal resistance	Rth(j-c)	Junction-to-case DC		-	_	8	°C/W	Refer to Figure 13.
	Rth(j-a)	Junction-to-am	bient DC	_	-	75		

TYPICAL CHARACTERISTICS (Ta = 25°C)



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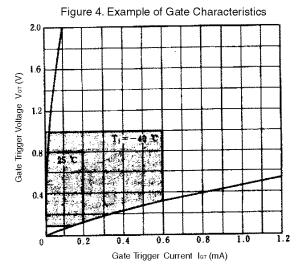
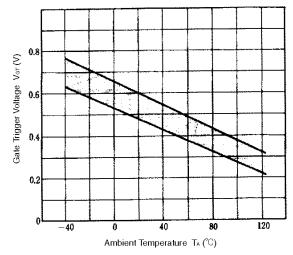
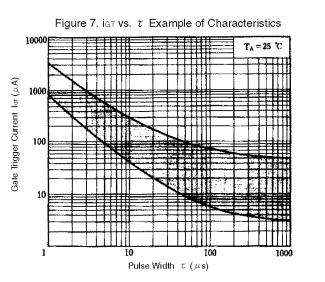
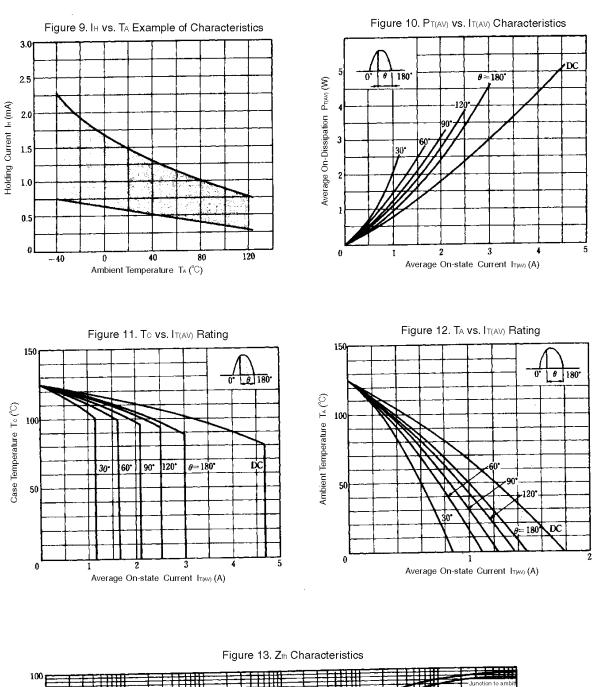


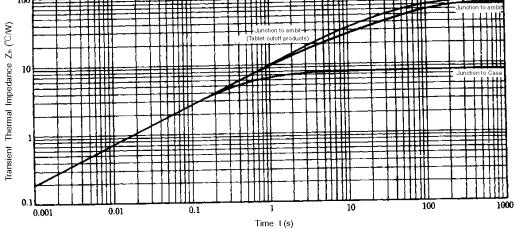
Figure 5. Ist vs. TA Example of Characteristics

Figure 6. VGT vs. TA Example of Characteristics









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[MEMO]

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